What is OghmaNano?

A tool for simulating: Organic solar cells, perovskites solar cells, OFETs and OLEDs. In time domain, steady state and frequency domain.





History of OghmaNano

- •Overview of model
 - •Electrical models
 - •Drift diffusion
 - •Circuit model
 - •Optical models.
 - Exciton models
 - •Simulation modes
 - •Thermal models
 - •Example simulation



•The development of OghmaNano was started at **Imperial college in 2011** to simulate organic solar cells, since then it has been rewritten many times.

•27/01/2012: The model was named the Organic Photovoltaic Device Model or **opvdm** and released to the web.

• **17/01/2016:** Due to the rising popularity of perovskites the model was renamed the (general purpose photovoltaic device model) or **gpvdm**.

14/10/2022: The model was renamed **OghmaNano** to reflect the fact that the model can now simulate many classes of devices including transistors. (**Org**anic and **h**ybrid **Ma**terial **Nano** Simulation tool)

•Today the model can simulate **solar cells**, **sensors**, **OFETs**, **OLEDs**, and **many more** classes of devices.



Overview of model

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•OghmaNano is a 1D/2D/3D opto-electronic device model, which can be used to simulate *solar cells*, *OLEDs*, *diodes*, *FETs* etc..

•Electrical models: 1D/2D drift diffusion models and 1D/2D/3D equivalent circuit models

•Optical models: Transfer matrix models in 1D/2D/3D, 3D ray tracing models, FDTD (beta).

- •Exciton models: Excitons, singlets, tripplets etc..
- •PL/EL models for emission
- •Simulation modes: Steady state, transient and FX-domain electrical models
- •Thermal models: Self heating



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Electrical simulation





•The most basic thing you can simulate when doing device simulation is the current voltage curves.

•Do simulate these you need to solve the drift diffusion equations.

Electrical simulations: Drift diffusion: Simulating charge transport



Gauss's Law

$$\nabla \epsilon_o \epsilon_r \cdot \nabla \phi = q \cdot (n-p)$$

Electron driving terms

$$J_n = q \,\mu_e \, n \,\nabla E_c + q \, D_n \nabla n$$

Electron continuity

$$\nabla \cdot \boldsymbol{J}_n = q \left(\boldsymbol{R}_n + \boldsymbol{T}_n + \frac{\partial \boldsymbol{n}_{free}}{\partial t} \right)$$

Hole driving terms $J_p = q \mu_h p \nabla E_v - q D_p \nabla p$

Hole continuity $\nabla \cdot \boldsymbol{J}_{p} = -q \left(R_{p} + T_{p} + \frac{\partial p_{free}}{\partial t} \right)$

•Fermi-dirac and and Maxwell-Boltzmann statistics

•Solved in 1D/2D

•In this respect OgmaNano is similar to many other device models, where it differs is in the inclusion of trap states..

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https://www.oghma-nano.com

Trap states are needed to simulate disordered/organic materials



 Inorganic semiconductors are crystalline and have a well defined bandgap and few traps.

 Inorganic semiconductors are very disordered and have a distribution of trap states.







Trapping: To do time domain simulations you need to assume carriers can more dynamically in and out of traps.



•We split energy space up into energy slices.

•And use the SRH equations but don't assume steady state, so solve the SRH equations explicitly in time domain. •Each trap state gets its own rate equation: ∂n •And use the SRH equations but don't

| $\partial n_{-r} - r_{-r} + r_{-r}$ | |
|--------------------------------------|--|
| $\partial t = r_1 - r_2 - r_3 + r_4$ | |

| Process | |
|-------------------|-------|
| electron capture | r_1 |
| electron emission | r_2 |
| hole capture | r_3 |
| hole emission | r_4 |



 Recombination can be calculated as:

Free carrier recombination



Detailed balance is maintained.

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The allows accurate simulation of steady state and transient measuements.



Drift diffusion: OghmaNano can also do 2D simulations including trap states







•To simulate disordered materials you need to include:

- •Carrier trapping
- •Recombination via trap states through a mechanism such as SRH.

•OghmaNano does is specifically written to do this very well:

- •If the device model you are using does not include trap states it is very likely you can not reliably simulate organic/disordered devices with it.
- •If you want to understand more watch this linked video.







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Electrical circuit simulation for large area devices: 3D electrical circuit simulations







Electrical circuit simulation for large area devices: 3D electrical circuit simulations





Really simple electrical circuit simulations:







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Overview.....

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Optics

Photon density

►

Run optical

. simulation

1.0

(a.u.) 8.0

0.6

0.2

0.0

-200

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편 0.4

About Wavelengths: Optical model: Solar spectrum: G 361 nm full Save graph Help 470 nm Photon Seneration rate Optical setup Photon distribution Photon distribution absorbed 471 nm 473 nm .70 eV -3.70 eV -3.80 eV 475 nm -4.17 e_{476 nm} -4.0 P3HT:PCBM 478 nm 480 nm DOT:PSS 470 Optical simulation editor (https://www.gpvdm.com) 481 nm ITO -4.90 eV 483 nm 484 nm Optics Wavelengths: Solar spectrum: Optical model: -5.80 eV Run optical 361 nm 🔻 full sun Save graph . simulation Photon absorbed Generation rate Optical setup Photon distribution Photon distribution absorbed Reflection -100 ò 100 200 Position (nm) Photon density 1e28 - 3.0 600 - 2.5 550 Wavelength (nm) - 2.0 500 - 1.5 450 - 1.0 400 - 0.5 -100 0 100 200 300 Position (nm)

Optical simulations: Transfer matrix method

Optical simulation editor (https://www.gpvdm.com)



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About

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Help

Optical simulations: General ray tracing solver





Optical simulations: FDTD solver





•The FDTD solver is currently fairly rudimentary



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Exciton models







https://www.youtube.com/watch?v=Viu7WYcbqyw

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Simulation modes: Steady state, time domain and frequency domain.



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Thermal models/self heating





Voltage - Lattice temperature



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Examples



